

IGBT MODULE (N series)

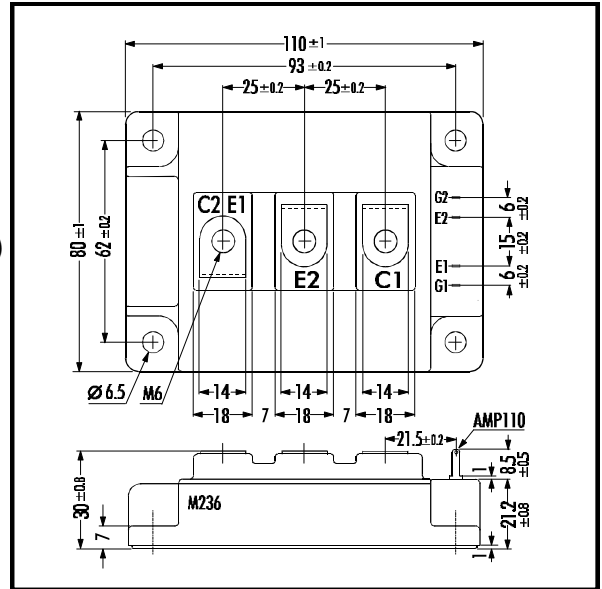
■ Features

- Square RBSOA
- Low Saturation Voltage
- Less Total Power Dissipation
- Improved FWD Characteristic
- Minimized Internal Stray Inductance
- Overcurrent Limiting Function (~3 Times Rated Current)

■ Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls
- Uninterruptible Power Supply

■ Outline Drawing



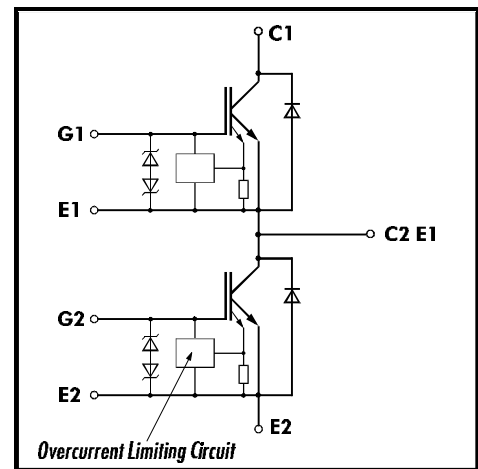
■ Maximum Ratings and Characteristics

• Absolute Maximum Ratings (T_c=25°C)

Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V _{CEs}	600	V
Gate -Emitter Voltage	V _{GES}	± 20	V
Collector Current	Continuous	I _C	600
	1ms	I _{C PULSE}	1200
	Continuous	-I _C	600
	1ms	-I _{C PULSE}	1200
Max. Power Dissipation	P _C	2100	W
Operating Temperature	T _j	+150	°C
Storage Temperature	T _{stg}	-40 ~ +125	°C
Isolation Voltage	V _{is}	2500	V
Screw Torque	Mounting *1	3.5	Nm
	Terminals *2	4.5	

Note: *1:Recommendable Value; 2.5 - 3.5 Nm (M5) or (M6)
*2:Recommendable Value; 3.5 - 4.5 Nm (M6)

■ Equivalent Circuit



• Electrical Characteristics (at T_J=25°C)

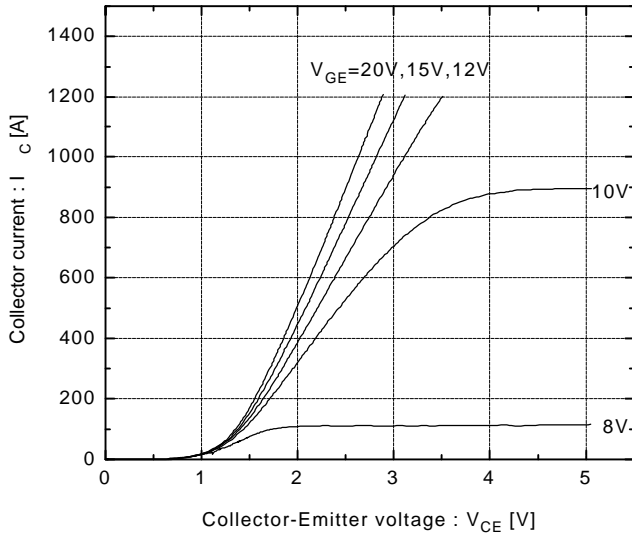
Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	I _{CEs}	V _{GE} =0V V _{CE} =600V			4.0	mA
Gate-Emitter Leakage Current	I _{GES}	V _{CE} =0V V _{GE} =± 20V			60	μA
Gate-Emitter Threshold Voltage	V _{GE(th)}	V _{GE} =20V I _C =600mA	4.5		7.5	V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} =15V I _C =600A			2.9	V
Input capacitance	C _{ies}	V _{GE} =0V		39600		pF
Output capacitance	C _{oes}	V _{CE} =10V		8800		
Reverse Transfer capacitance	C _{res}	f=1MHz		2670		
Turn-on Time	t _{ON}	V _{CC} =300V		0.6	1.2	μs
	t _r	I _C =600A		0.2	0.6	
Turn-off Time	t _{OFF}	V _{GE} =± 15V		0.6	1.0	
	t _f	R _G =2.7Ω		0.2	0.35	
Diode Forward On-Voltage	V _F	I _F =600A V _{GE} =0V			3.1	V
Reverse Recovery Time	t _{rr}	I _F =600A			300	ns

• Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	R _{th(j-c)}	IGBT			0.06	°C/W
	R _{th(j-e)}	Diode			0.15	
	R _{th(c-f)}	With Thermal Compound		0.0167		

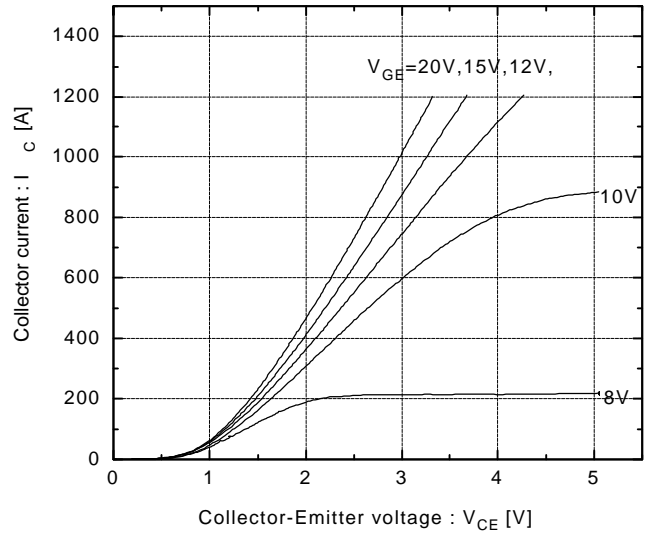
Collector current vs. Collector-Emittor voltage

$T_j=25^\circ\text{C}$



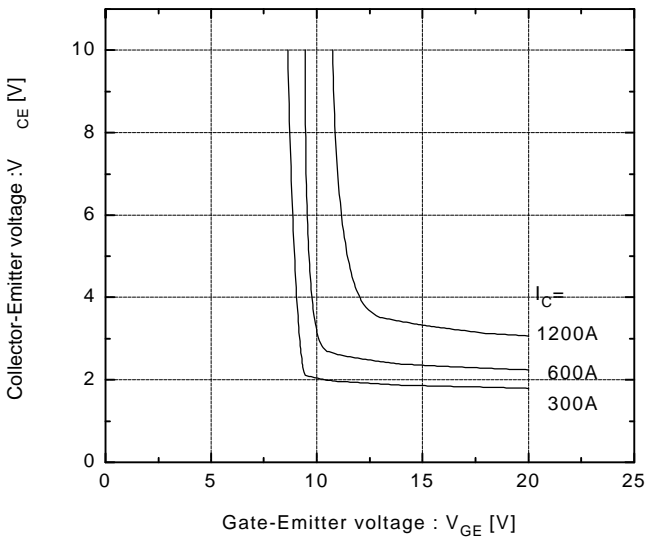
Collector current vs. Collector-Emittor voltage

$T_j=125^\circ\text{C}$



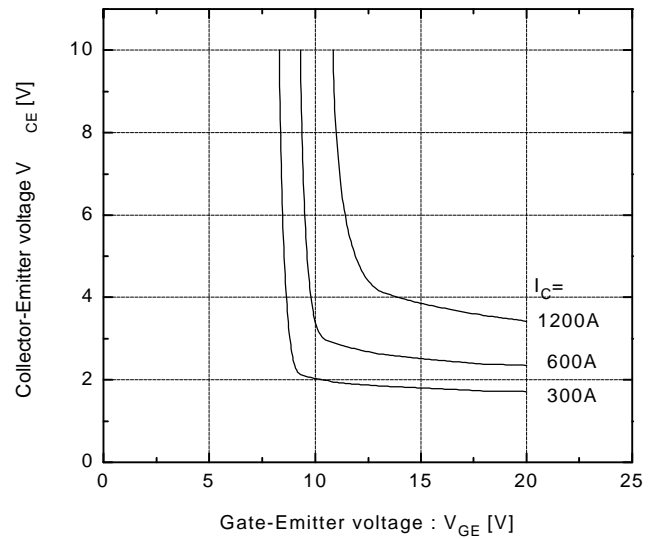
Collector-Emittor vs. Gate-Emittor voltage

$T_j=25^\circ\text{C}$

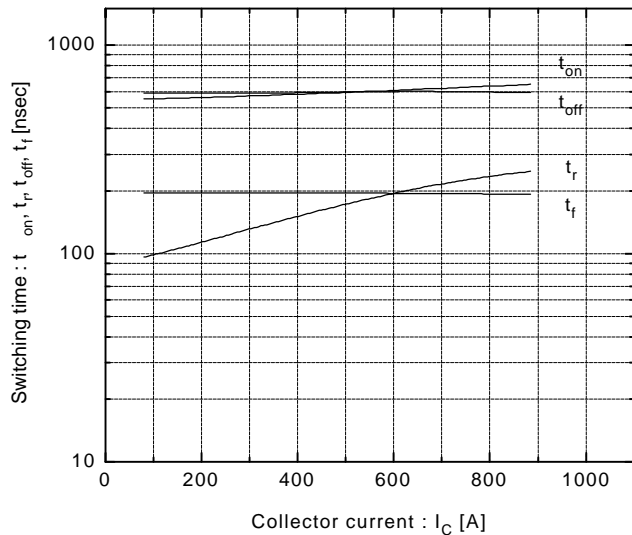


Collector-Emittor vs. Gate-Emittor voltage

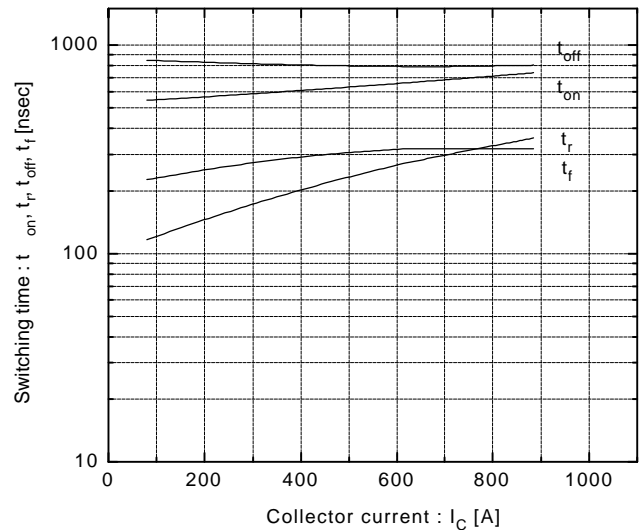
$T_j=125^\circ\text{C}$



Switching time vs. Collector current
 $V_{CC}=300\text{V}, R_G=2.7\Omega, V_{GE}=\pm 15\text{V}, T_j=25^\circ\text{C}$

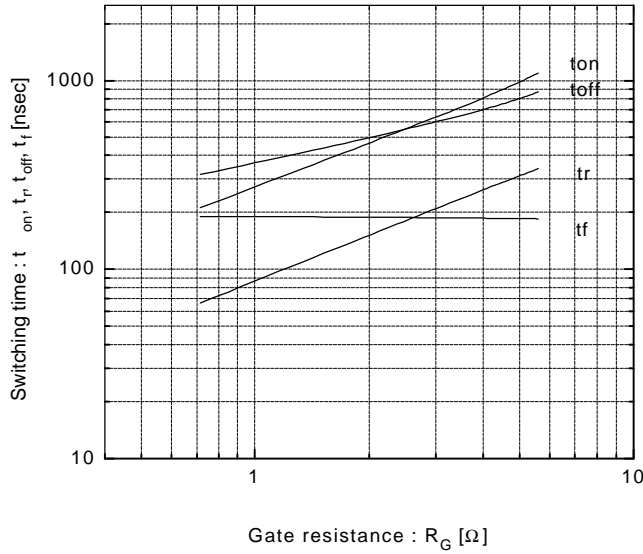


Switching time vs. Collector current
 $V_{CC}=300\text{V}, R_G=2.7\Omega, V_{GE}=\pm 15\text{V}, T_j=125^\circ\text{C}$



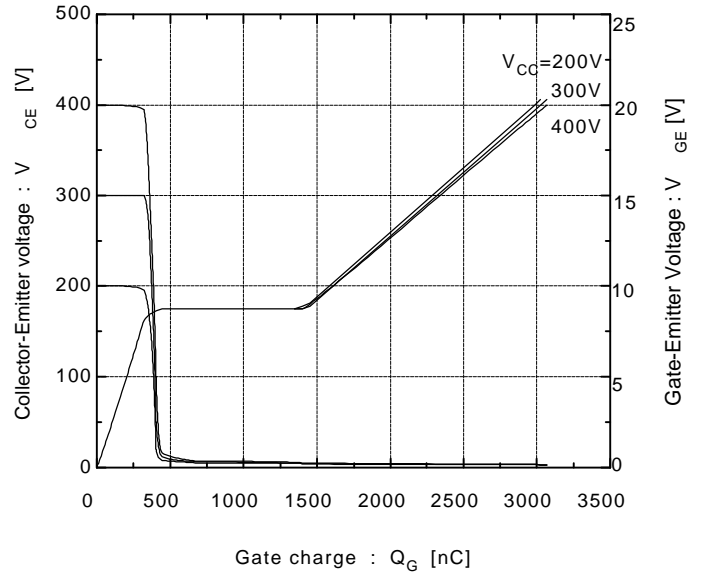
Switching time vs. R_G

$V_{CC}=300V, I_C=600A, V_{GE}=\pm 15V, T_J=25^\circ C$



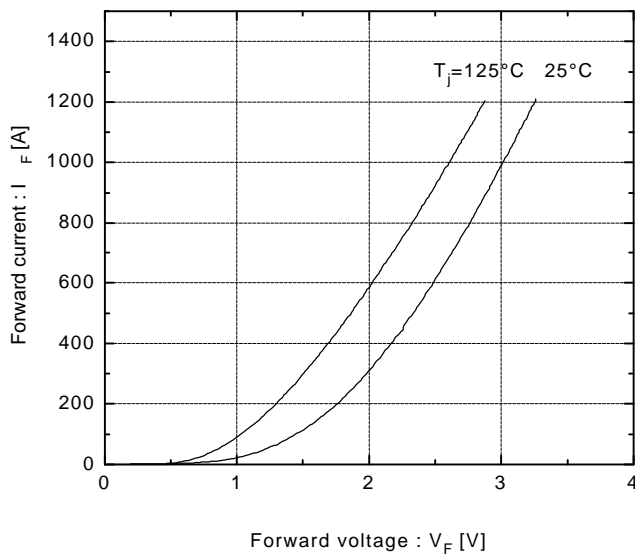
Dynamic input characteristics

$T_J=25^\circ C$



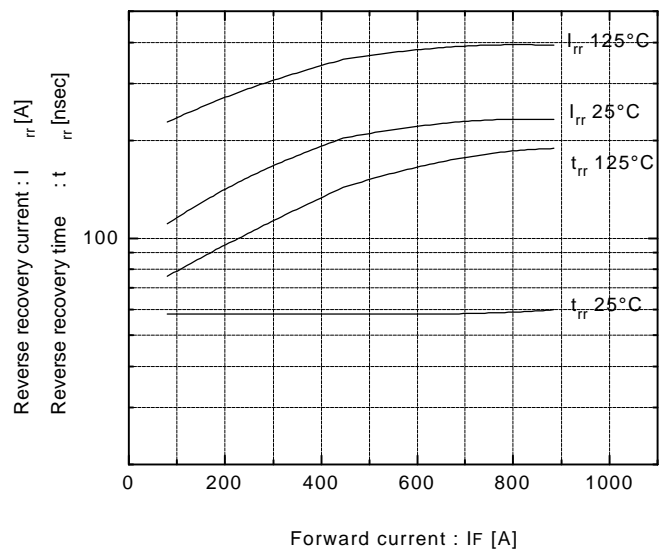
Forward current vs. Forward voltage

$V_{GE}=0V$

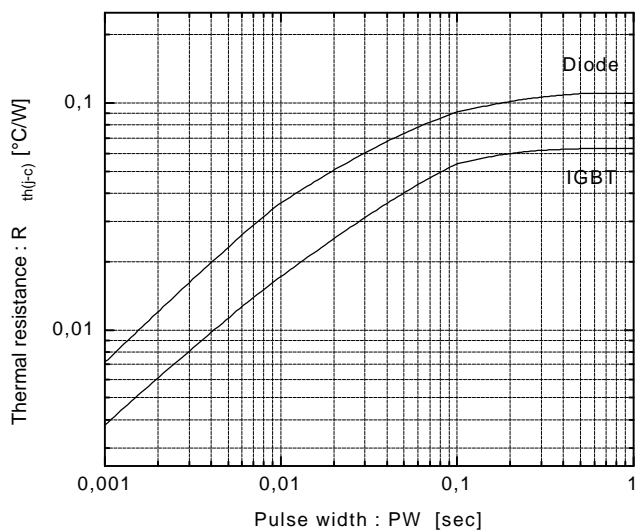


Reverse recovery characteristics

t_{rr}, I_{rr} vs. I_F

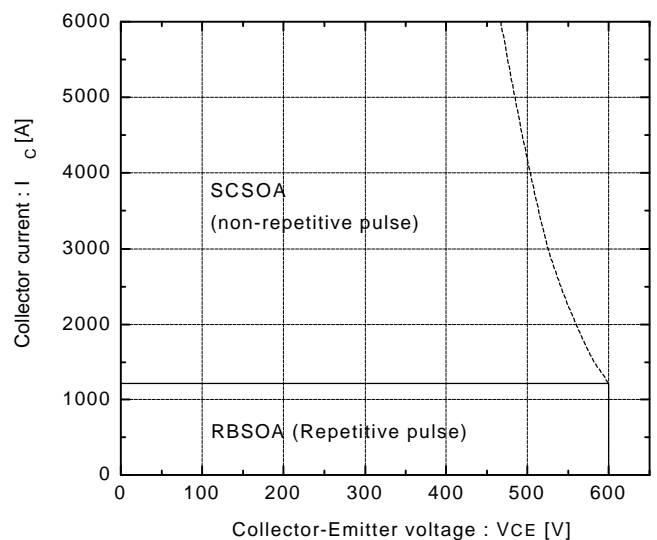


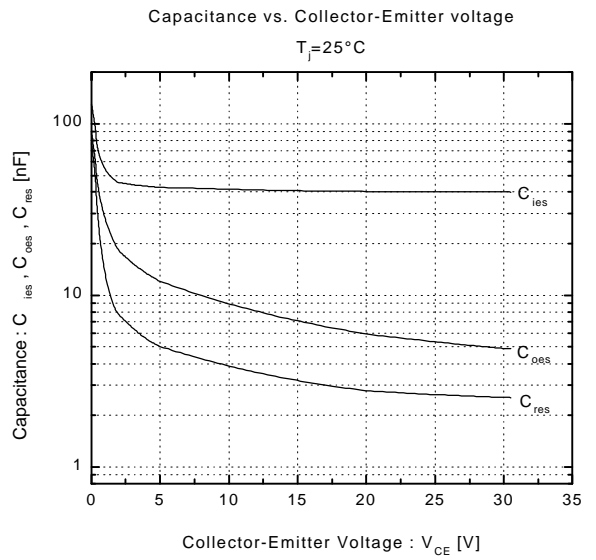
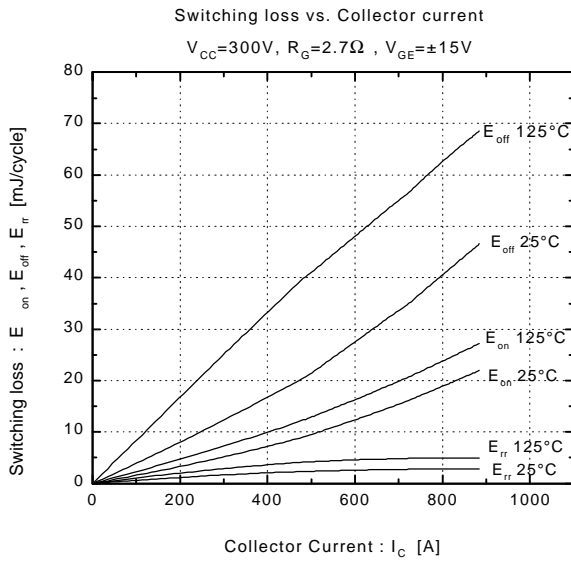
Transient thermal resistance



Reversed biased safe operating area

$+V_{GE}=15V, -V_{GE}\leq 15V, T_J\leq 125^\circ C, R_G\geq 2.7\Omega$





Fuji Electric GmbH

Lyoner Straße 26

D-60528 Frankfurt/M

Tel.: 069 - 66 90 29 - 0

Fax.: 069 - 66 90 29 - 56

Fuji Electric (UK) Ltd.

Commonwealth House
 2 Chalkhill Road Hammersmith

London W6 8DW, UK

Tel.: 0181 - 233 11 30

Fax.: 0181 - 233 11 60